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Stocking Distributor

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[IXYS Corporation](#)

[VUO105-16NO7](#)

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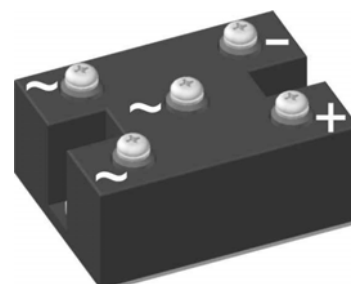
Standard Rectifier Module

3~ Rectifier	
V_{RRM}	= 1600 V
I_{DAV}	= 120 A
I_{FSM}	= 1500 A

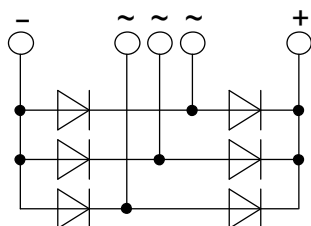
3~ Rectifier Bridge

Part number

VUO105-16NO7



 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

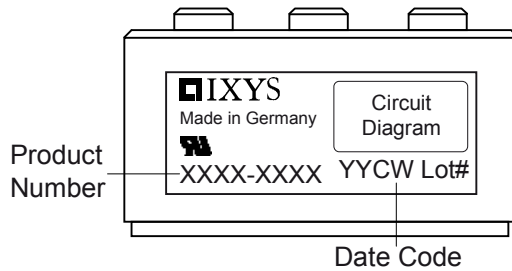
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: PWS-C

- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Rectifier				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage				1700	V	
V_{RRM}	max. repetitive reverse blocking voltage				1600	V	
I_R	reverse current	$V_R = 1600\text{ V}$	$T_{VJ} = 25^\circ\text{C}$		100	μA	
		$V_R = 1600\text{ V}$	$T_{VJ} = 150^\circ\text{C}$		2	mA	
V_F	forward voltage drop	$I_F = 40\text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.09	V	
					1.38	V	
		$I_F = 120\text{ A}$	$T_{VJ} = 125^\circ\text{C}$		1.00	V	
					1.36	V	
I_{DAV}	bridge output current	$T_C = 105^\circ\text{C}$ rectangular $d = 1/3$	$T_{VJ} = 150^\circ\text{C}$		120	A	
V_{F0}	threshold voltage	} for power loss calculation only	$T_{VJ} = 150^\circ\text{C}$		0.78	V	
r_F	slope resistance				4.8	m Ω	
R_{thJC}	thermal resistance junction to case				0.8	K/W	
R_{thCH}	thermal resistance case to heatsink			0.30		K/W	
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		155	W	
I_{FSM}	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^\circ\text{C}$		1.50	kA	
					1.62	kA	
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$	$T_{VJ} = 150^\circ\text{C}$		1.28	kA
						1.38	kA
I^2t	value for fusing	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^\circ\text{C}$		11.3	kA ² s	
					10.9	kA ² s	
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$	$T_{VJ} = 150^\circ\text{C}$		8.13	kA ² s
						7.87	kA ² s
C_J	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	58		pF	

Package PWS-C		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			150	A
T_{stg}	storage temperature		-40		125	°C
T_{vj}	virtual junction temperature		-40		150	°C
Weight				250		g
M_D	mounting torque		4.25		5.75	Nm
M_T	terminal torque		4.25		5.75	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	26.0			mm
$d_{Spb/Apb}$		terminal to backside	14.0			mm
V_{ISOL}	isolation voltage	t = 1 second	3000			V
		t = 1 minute	2500			V



Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO105-16NO7	VUO105-16NO7	Box	10	456748

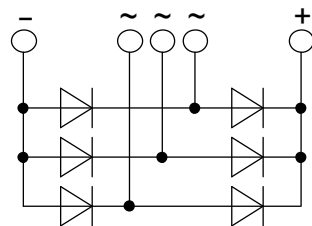
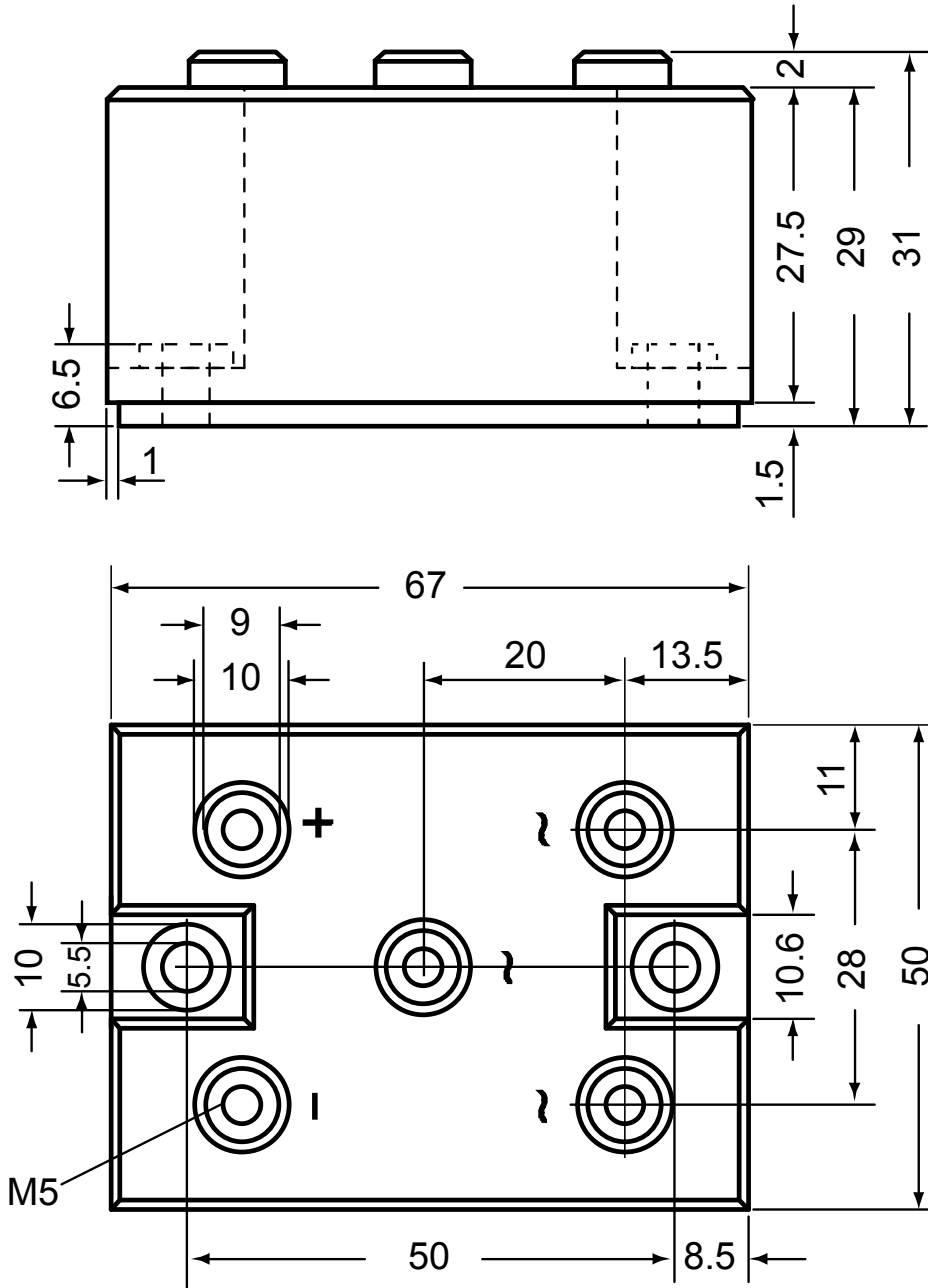
Equivalent Circuits for Simulation

* on die level

$T_{vj} = 150^\circ\text{C}$

Symbol	Definition	Value	Unit
V_0	threshold voltage	0.78	V
R_0	slope resistance *	3.6	mΩ

Outlines PWS-C



Rectifier

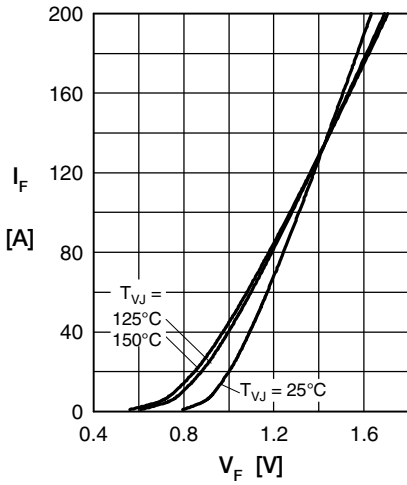


Fig. 1 Forward current versus voltage drop per diode

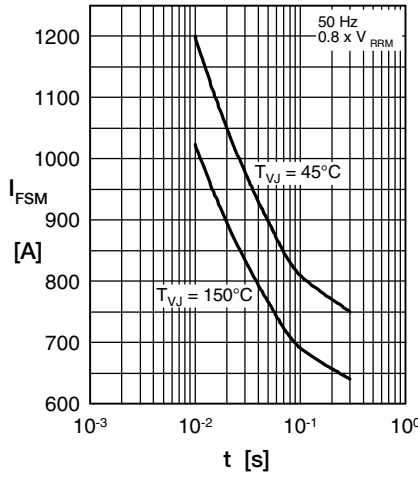


Fig. 2 Surge overload current vs. time per diode

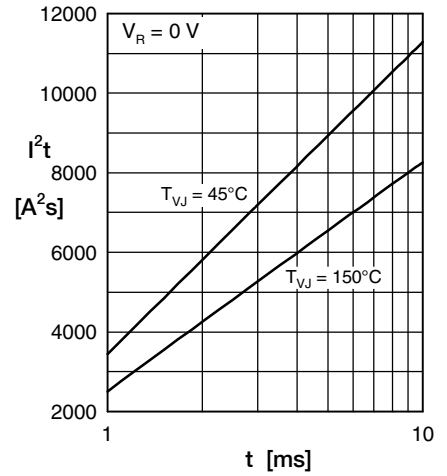


Fig. 3 I^2t versus time per diode

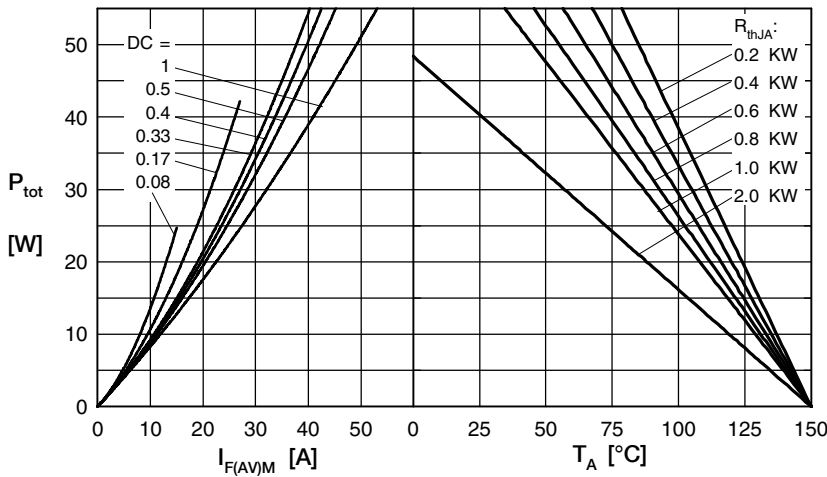


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

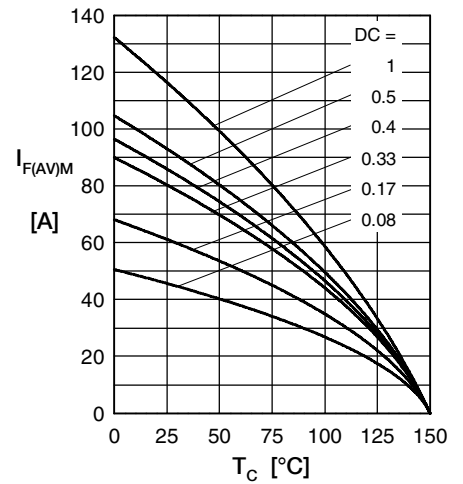


Fig. 5 Max. forward current vs. case temperature per diode

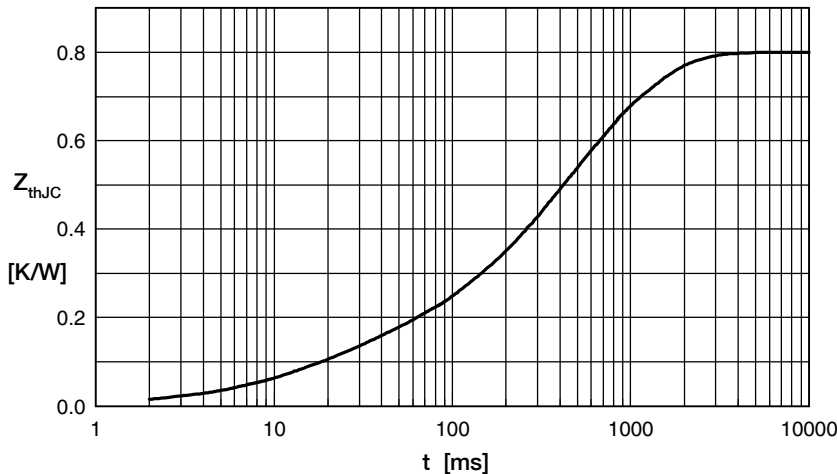


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.100	0.020
2	0.014	0.010
3	0.192	0.225
4	0.281	0.800
5	0.213	0.580